

TS8329K - 100W Asymmetric Peak Power GaN Broadband SPDT Switch

1.0 Features

- Low insertion loss (TX/RX): 0.4/0.5dB @ 3000MHz
- High isolation (RX Path): 38dB @ 3000MHz
- High peak power handling capability
- No external DC blocking capacitors on RF lines
- All RF ports OFF state
- Versatile 2.6-5.5V power supply
- Operating frequency: 500MHz to 5GHz

RF lines



Figure 1 Device Image (16 Pin 3×3×0.8mm QFN Package)

TTSW

TS8329K

2.0 Applications

- 4G, 5G systems
- RX protection
- Cellular infrastructure
- Small cells
- LTE relays and microcells
- Radar



RoHS/REACH/Halogen Free Compliance

3.0 Description

The TS8329K is an asymmetrical reflective Single Pole Dual Throw (SPDT) switch designed for broadband, high peak power switching applications. Its broadband behavior from 500MHz to 5GHz frequencies makes the TS8329K an excellent switch for all applications requiring low insertion loss, high isolation and high linearity within a small package size.

The TS8329K is packaged into a compact Quad Flat No lead (QFN) 3x3mm 16 leads plastic package.

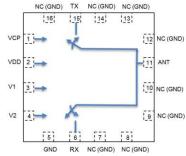


Figure 2 Function Block Diagram (Top View)

4.0 Ordering Information

Table 1 Ordering Information

Base Part Number	Package Type	Form	Qty	Reel Diameter	Reel Width	Orderable Part Number
TS8329K	16 Pin 3×3×0.8mm QFN	Tape and Reel	3000	13" (330mm)	18mm	TS8329KMTRPBF
Evaluation Board						TS8329K-EVB



5.0 Pin Description

Table 2 Pin Definition

Pin Number	Pin Name	Description
1	VCP	Internal charge pump voltage output. Connect a 1nF capacitor to
'		GND on this pin to improve switching time.
2	VDD	DC power supply
3	V1	Switch control input 1
4	V2	Switch control input 2
5	GND	Ground
6	RX	RX port
7,8,9,10,12,13,14,16	NC	No internal connection, Can be grounded
11	ANT	Antenna port
15	TX	TX port

Note: The backside ground (thermal) pad of the package must be grounded directly to the ground plane of PCB with multiple vias to ensure proper operation and thermal management.

6.0 Absolute Maximum Ratings

Table 3 Absolute Maximum Ratings @T_{A=+25°C} Unless Otherwise Specified

Parameter	Symbol	Value	Unit				
Electrical Ratings							
Power Supply Voltage	VDD	2.6 to 5.5	V				
Storage Temperature Range	T _{st}	-55 to +125	°C				
Operating Temperature Range	T _{op}	-40 to +85	°C				
Maximum Junction Temperature	TJ	+140	°C				
RF Input Power CW, 800MHz, T _J =+85°C	TX-ANT	42	dBm				
RF Input Power CW, 800MHz, T _J =+105°C	TX-ANT	41	dBm				
Thermal Rati	ings						
Thermal Resistance (junction-to-case) – Bottom side ReJC 25 °C/V							
Thermal Resistance (junction-to-top)	R _θ ЈТ	36	°C/W				
Soldering Temperature	T _{SOLD}	260	°C				
ESD Ratings							
Human Body Model (HBM)	Level 1B	500 to <1000	V				
Charged Device Model (CDM)	Level C3	≥1000	V				
Moisture Rating							
Moisture Sensitivity Level MSL 1							

Attention:

Maximum ratings are absolute ratings. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Exceeding one or a combination of the absolute maximum ratings may cause permanent and irreversible damage to the device and/or to surrounding circuit.





7.0 Electrical Specifications

Table 4 Electrical Specifications @T_A=+25°C Unless Otherwise Specified; VDD=+3.3V; 50Ω Source/Load.

	ecifications @TA=+25 C Offices Otherwise					
Parameter	Condition	Minimum	Typical	Maximum	Unit	
Operating Frequency		500		5000	MHz	
Insertion Loss, TX	800MHz		0.30	0.40	dB	
	1.95GHz		0.35	0.45		
	2.6GHz		0.38	0.55		
	3.8GHz		0.40			
	5.0GHz		0.45			
Insertion Loss, RX	800MHz		0.34	0.65	dB	
	1.95GHz		0.40	0.70		
	2.6GHz		0.45	0.75		
	3.8GHz		0.60			
	5.0GHz		0.70			
Isolation ANT-TX	800MHz	39	48		dB	
	1.95GHz	30	36			
	2.6GHz	27	32			
	3.8GHz		25			
	5.0GHz		21			
Isolation ANT-RX	800MHz	52	58		dB	
	1.95GHz	42	46			
	2.6GHz	37	41			
	3.8GHz		35			
	5.0GHz		32			
Return Loss	800MHz		25		dB	
ANT-TX, RX	1.95GHz		23			
	2.6GHz		22			
	3.8GHz		17			
	5.0GHz		14			
Isolation @ Peak	Peak power=49.2dBm, Isolation RX		0.5		ID.	
Power	@3.8GHz		35		dB	
	Harmonic distortion					
H2	800MHz, Pin=35dBm		-40		dBm	
H3	800MHz, Pin=35dBm		-45		dBm	
IIP3	800MHz		71		dBm	
P0.1dB ^[1] TX	700MHz~3.8GHz, CW	42	44		dBm	
Peak P0.1dB TX ^[2]	700MHz~3.8GHz, pulsed power	49.2	50		dBm	
P0.1dB ^[1] RX	700MHz~3.8GHz, CW	39			dBm	
	50% ctrl to 10/90% of the RF value is		0.4			
Switching Time	settled. C1=1nF (refer to Figure 3)		0.4		μS	
Control Voltage	Power supply VDD	2.6	3.3	5.5	V	
	All control pins high, V _{ih}	1.0	3.3	5.25	V	
	All control pins low, V _{ii}	-0.3		0.5	V	
Control Current	All control pins low, Iii		0		μΑ	
	All control pins high, lih			7.5	μA	
Current	1 •		400			
Consumption, IDD	Active mode		160	200	μΑ	

Note:

- [1] P0.1dB is a figure of merit.
- [2] 1% duty cycle and 10µs pulse width.
- [3] No external DC blocking capacitors required on RF pins unless DC voltage is applied on a RF pin.



8.0 Switch Truth Table

Table 5 Switch Truth Table

V1	V2	Active RF Path
0	1	All OFF
0	0	ANT-RX
1	0	ANT-TX

Attention:

- [1] VDD should be applied first before V1 and V2, otherwise may cause damage to the device.
- [2] There are internal pull-downs to ground on both V1 and V2 control pins, the state at start-up without any control voltage applied will be ANT-TX ON.
- [3] If all OFF state is not used, the switch can be operated with single control pin V1.

9.0 Evaluation Board

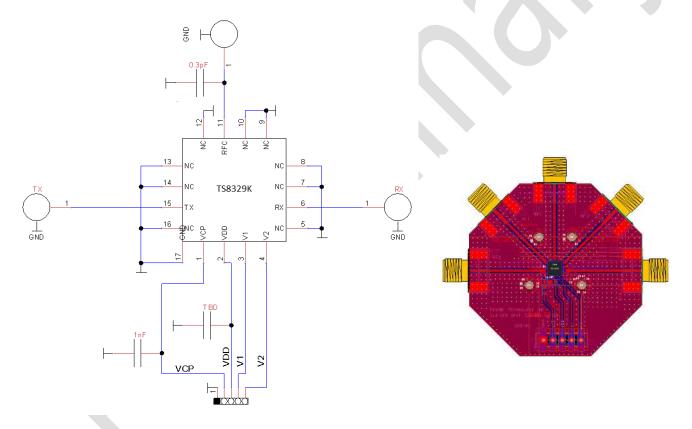


Figure 3 Evaluation Board Schematic

Figure 4 Evaluation Board Image

Attention:

- [1] 17 refers to the center pad of the device.
- [2] The purpose of connection between VCP and connector N1 is to monitor VCP, do not apply external voltage to VCP.
- [3] Below 4GHz, no match required on ANT port.
- [4] For 4.4~5GHz: Add 0.3pF (Passive Plus 0402N0R3AW251) to GND close to RFC pin.



10.0 Typical Characteristics

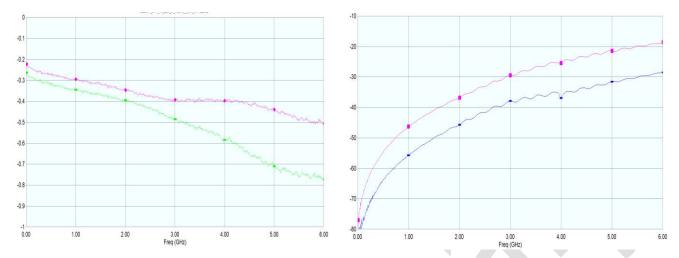


Figure 5 TX, RX Insertion Loss

Figure 6 TX, RX Isolation

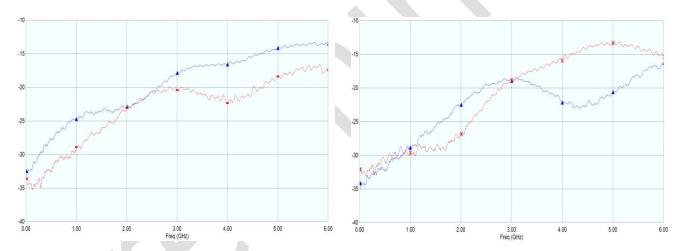


Figure 7 TX, RX Return Loss

Figure 8 ANT Return Loss

11.0 Device Package Information

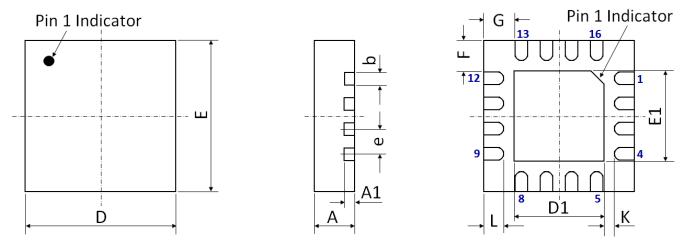


Figure 13 Device Package Drawing (All dimensions are in mm)

Table 6 Device Package Dimensions

Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)		
Α	0.80	±0.05	E	3.00 BSC	±0.05		
A1	0.203	±0.02	E1	1.70	±0.05		
b	0.25	±0.05	F	0.625	±0.05		
D	3.00 BSC	±0.05	G	0.625	±0.05		
D1	1.70	±0.05	K	0.25	±0.05		
е	0.50 BSC	±0.05	L	0.40	±0.05		

Note: Lead finish: Pure Sn without underlayer; Thickness: 7.5μm ~ 20μm (Typical 10μm ~ 12μm)

Attention:

Please refer to application notes *TN-001* and *TN-002* at http://www.tagoretech.com for PCB and soldering related guidelines.

12.0 PCB Land Design

Guidelines:

- [1] 4 layer PCB is recommended.
- [2] Via diameter is recommended to be 0.2mm to prevent solder wicking inside the vias.
- [3] Thermal vias shall only be placed on the center pad.
- [4] The maximum via number for the center pad is $3(X)\times3(Y)=9$.

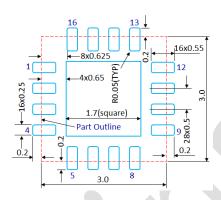


Figure 14 PCB Land Pattern (Dimensions are in mm)



Figure 15 Solder Mask Pattern

(Dimensions are in mm)

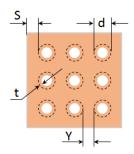


Figure 16 Thermal Via Pattern

(Recommended Values: S≥0.15mm; Y≥0.20mm; d=0.2mm; Plating Thickness t=25µm or 50µm)

13.0 PCB Stencil Design

Guidelines:

- [1] Laser-cut, stainless steel stencil is recommended with electro-polished trapezoidal walls to improve the paste release.
- [2] Stencil thickness is recommended to be 125µm.

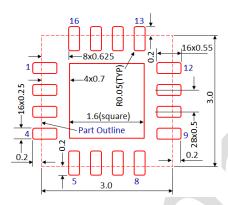


Figure 17 Stencil Openings

(Dimensions are in mm)

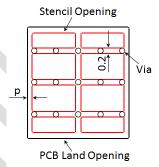


Figure 18 Stencil Openings Shall not Cover Via Areas If Possible (Dimensions are in mm)

14.0 Tape and Reel Information

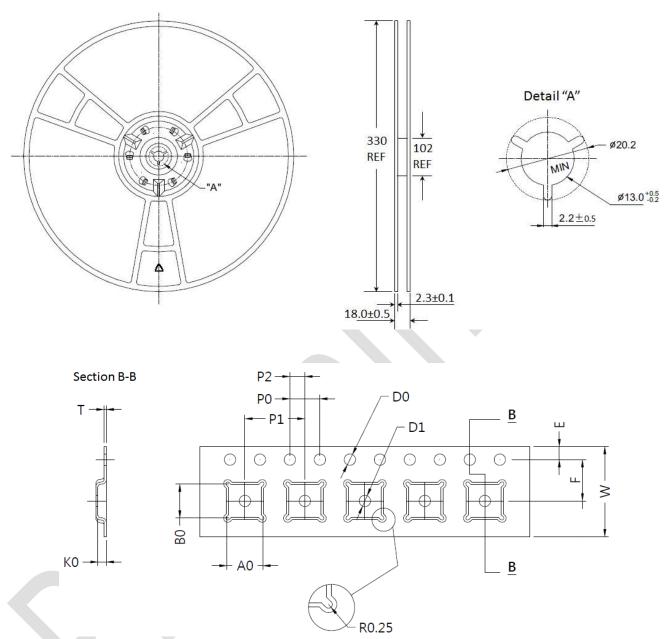


Figure 19 Tape and Reel Drawing

Table 7 Tape and Reel Dimensions

Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)
A0	3.35	±0.10	K0	1.10	±0.10
В0	3.35	±0.10	P0	4.00	±0.10
D0	1.50	+0.10/-0.00	P1	8.00	±0.10
D1	1.50	+0.10/-0.00	P2	2.00	±0.05
E	1.75	±0.10	Т	0.30	±0.05
F	5.50	±0.05	W	12.00	±0.30



Edition Revision 0.3 - 2022-07-21

Published by

Tagore Technology Inc. 5 East College Drive, Suite 200 Arlington Heights, IL 60004, USA

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